

## SWITCHING

## N-CHANNEL POWER MOS FET

### DESCRIPTION

The 2SK3109 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for high voltage applications such as DC/DC converter.

### ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3109	TO-220AB (MP-25)
2SK3109-S	TO-262 (MP-25 Fin Cut)
2SK3109-ZJ	TO-263 (MP-25ZJ)

### FEATURES

- Gate voltage rating  $\pm 30$  V
- Low on-state resistance  
 $R_{DS(on)} = 0.4 \Omega$  MAX. ( $V_{GS} = 10$  V,  $I_D = 5.0$  A)
- Low input capacitance  
 $C_{iss} = 400$  pF TYP. ( $V_{DS} = 10$  V,  $V_{GS} = 0$  V)
- Avalanche capability rated
- Built-in gate protection diode
- Surface mount device available

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

Drain to Source Voltage ( $V_{GS} = 0$ V)	$V_{DSS}$	200	V
Gate to Source Voltage ( $V_{DS} = 0$ V)	$V_{GSS}$	$\pm 30$	V
Drain Current (DC) ( $T_C = 25^\circ\text{C}$ )	$I_{D(DC)}$	$\pm 10$	A
Drain Current (pulse) <sup>Note1</sup>	$I_{D(pulse)}$	$\pm 30$	A
Total Power Dissipation ( $T_A = 25^\circ\text{C}$ )	$P_{T1}$	1.5	W
Total Power Dissipation ( $T_C = 25^\circ\text{C}$ )	$P_{T2}$	50	W
Channel Temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	$-55$ to $+150$	$^\circ\text{C}$
Single Avalanche Current <sup>Note2</sup>	$I_{AS}$	10	A
Single Avalanche Energy <sup>Note2</sup>	$E_{AS}$	35	mJ

**Notes 1.**  $PW \leq 10 \mu\text{s}$ , Duty Cycle  $\leq 1\%$

**2.** Starting  $T_{ch} = 25^\circ\text{C}$ ,  $V_{DD} = 100$  V,  $R_G = 25 \Omega$ ,  $V_{GS} = 20 \rightarrow 0$  V

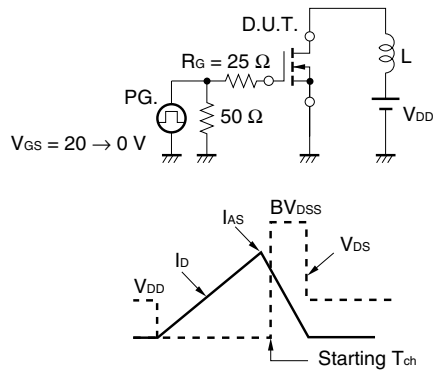
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★ ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

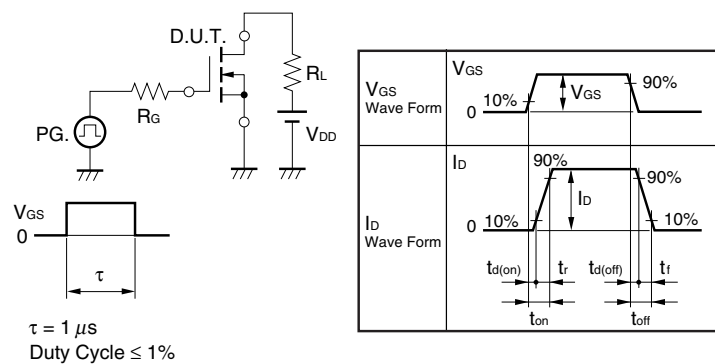
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 200 V, V <sub>GS</sub> = 0 V			100	μA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±30 V, V <sub>DS</sub> = 0 V			±10	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.5		4.5	V
Forward Transfer Admittance <b>Note</b>	y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 5.0 A	1.5			S
Drain to Source On-state Resistance <b>Note</b>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 5.0 A		0.32	0.4	Ω
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10 V,		400		pF
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V,		110		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1 MHz		55		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 100 V, I <sub>D</sub> = 5.0 A,		12		ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = 10 V,		34		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 10 Ω		40		ns
Fall Time	t <sub>f</sub>			20		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = 160 V,		18		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = 10 V,		3.5		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = 10 A		10		nC
Body Diode Forward Voltage <b>Note</b>	V <sub>F(S-D)</sub>	I <sub>F</sub> = 10 A, V <sub>GS</sub> = 0 V		1.0		V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 10 A, V <sub>GS</sub> = 0 V,		250		ns
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt = 50 A/μs		1.0		μC

**Note** Pulsed

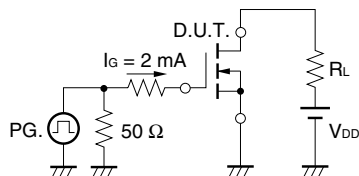
TEST CIRCUIT 1 AVALANCHE CAPABILITY



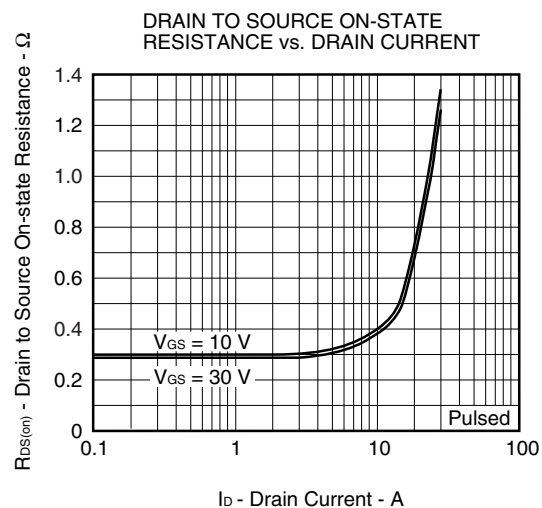
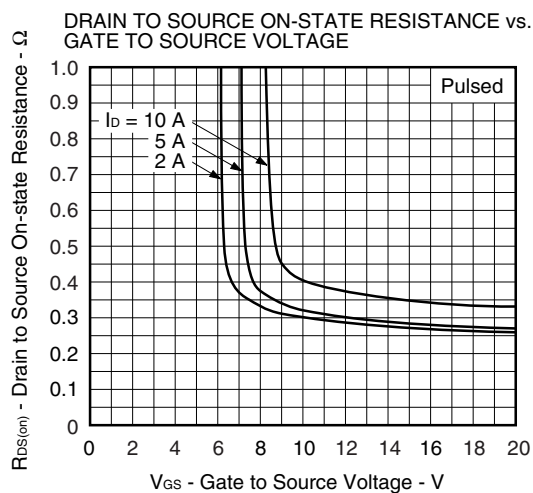
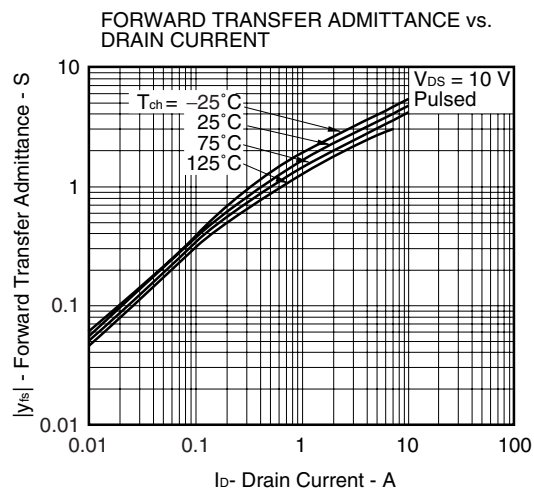
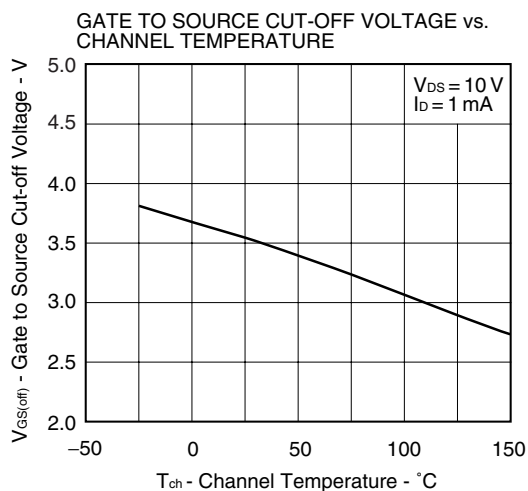
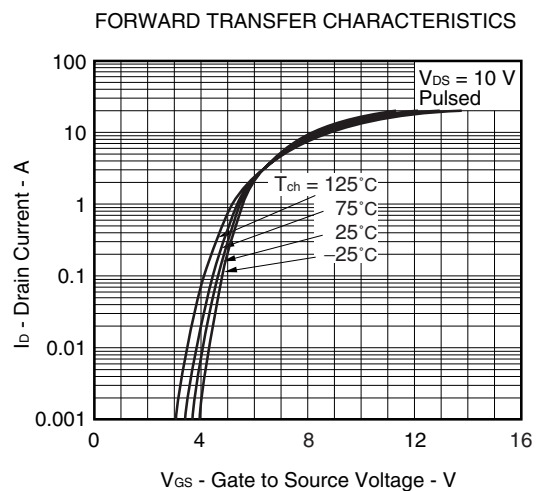
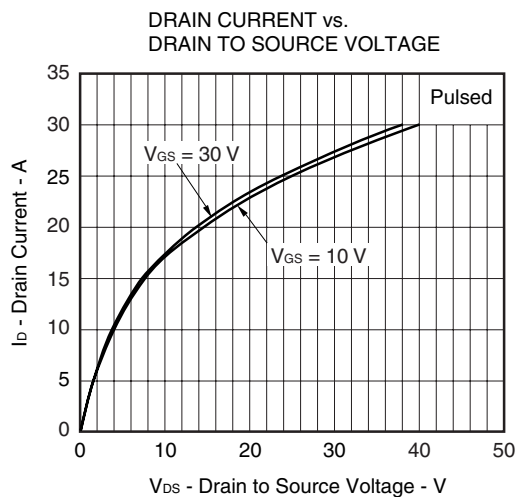
TEST CIRCUIT 2 SWITCHING TIME

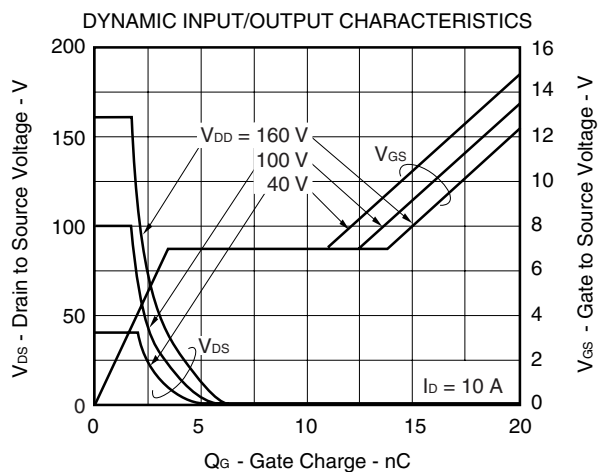
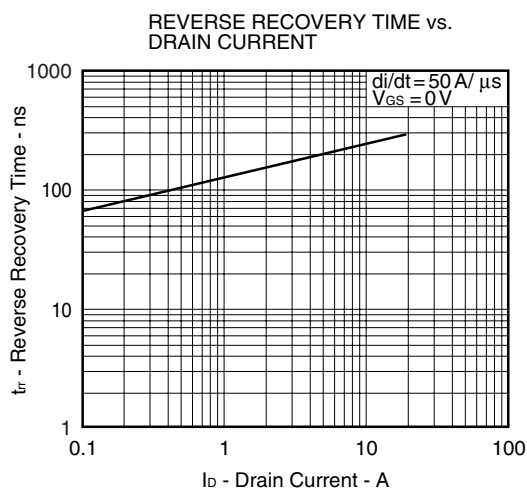
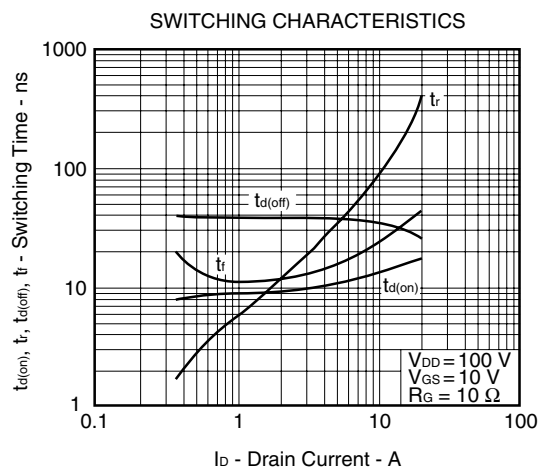
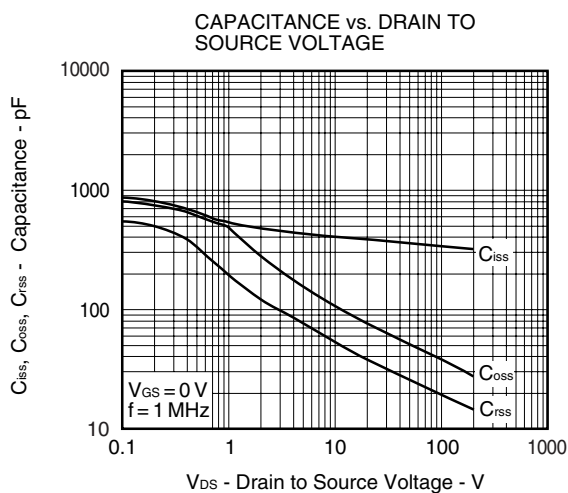
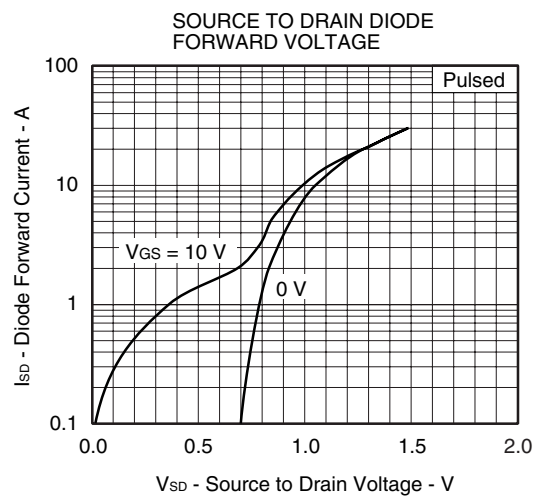
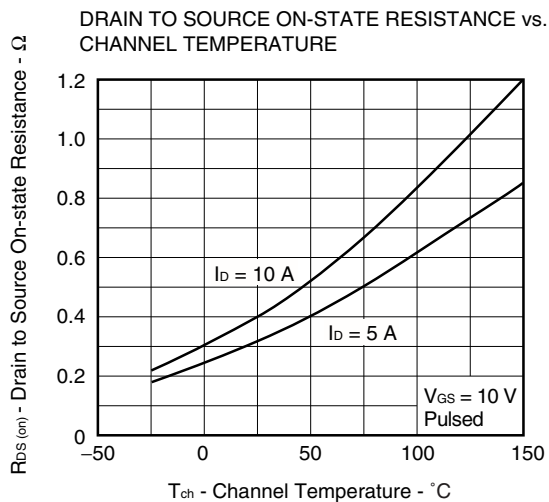


TEST CIRCUIT 3 GATE CHARGE

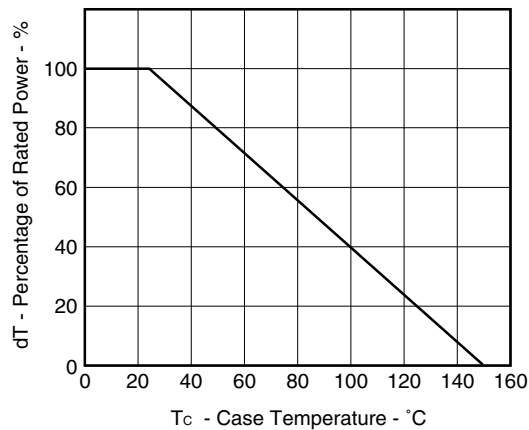


TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )

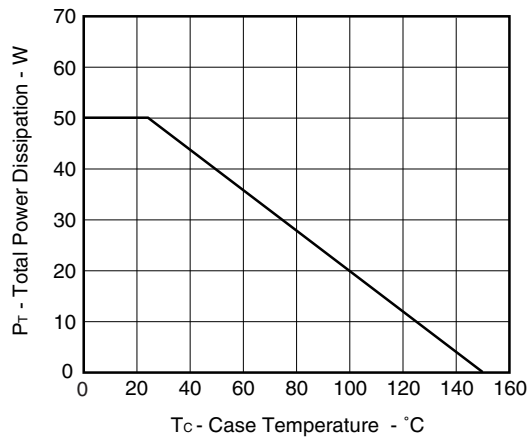




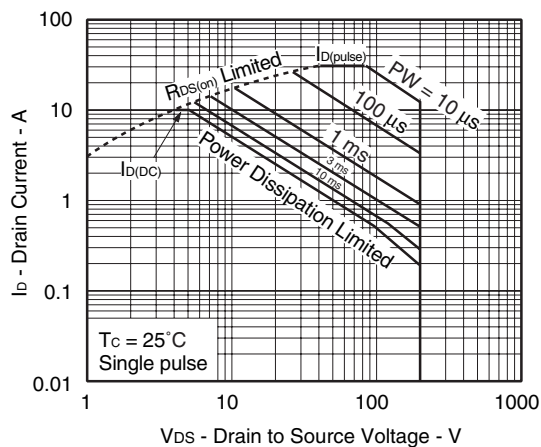
DERATING FACTOR OF FORWARD BIAS  
SAFE OPERATING AREA



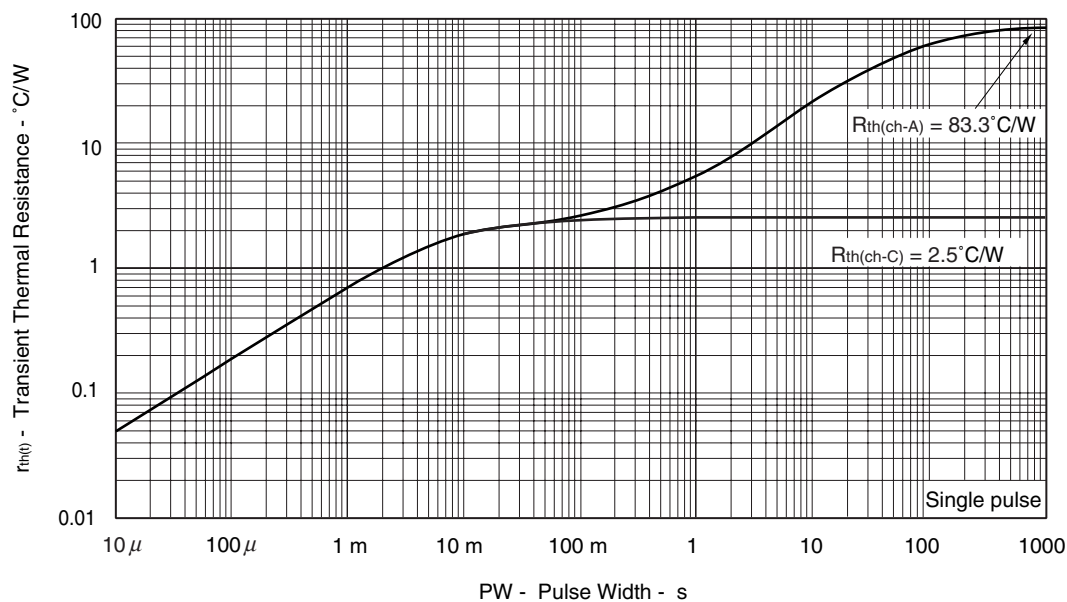
TOTAL POWER DISSIPATION vs.  
CASE TEMPERATURE

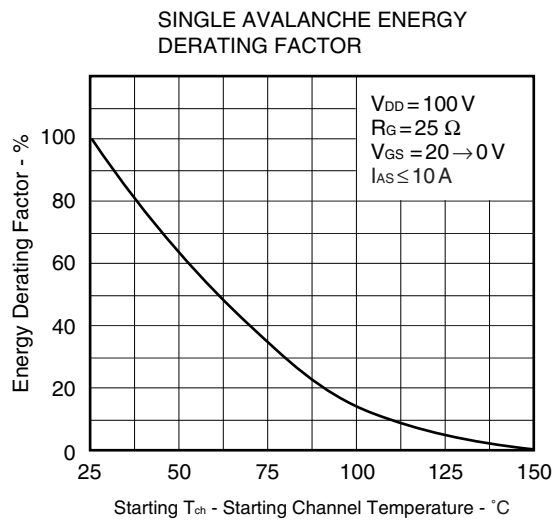
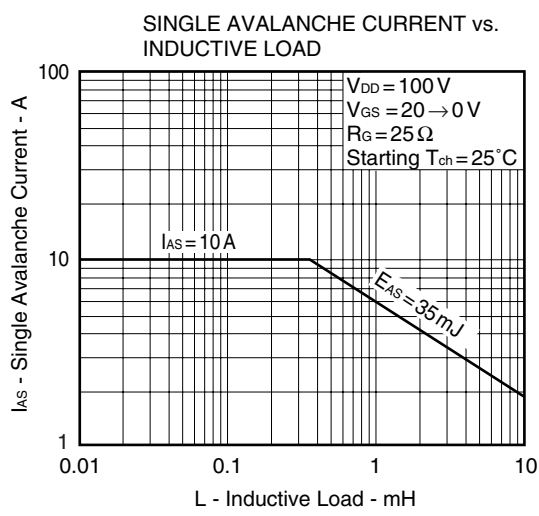


FORWARD BIAS SAFE OPERATING AREA



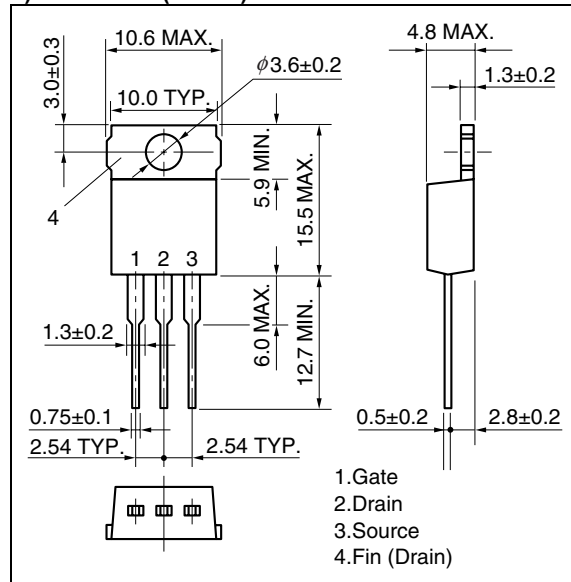
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



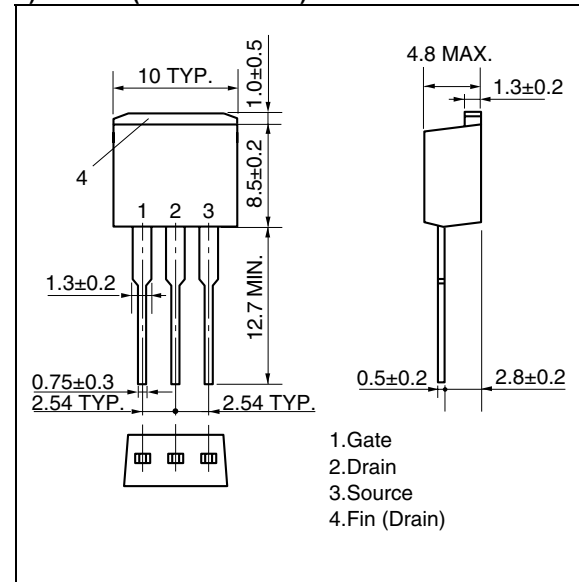


★ PACKAGE DRAWINGS (Unit: mm)

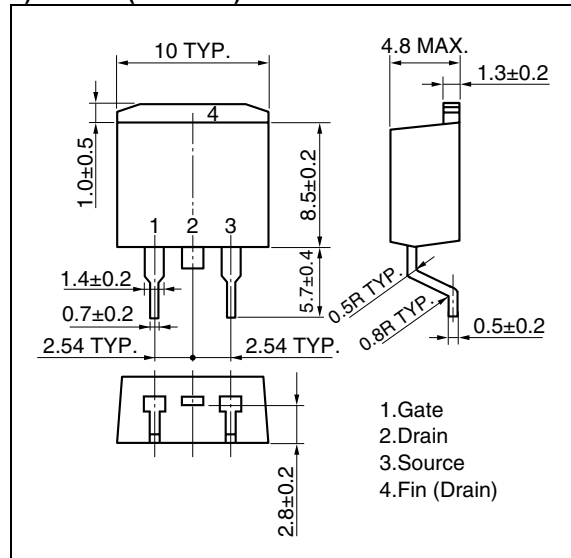
1) TO-220AB (MP-25)



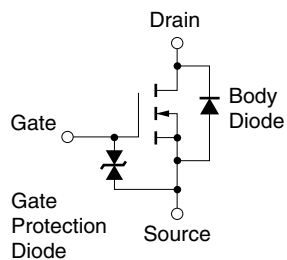
2) TO-262 (MP-25 Fin Cut)



3) TO-263 (MP-25ZJ)



EQUIVALENT CIRCUIT



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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